

# Electrostatic Measurement Issues and SEMI E43

标准  
Normen  
規格  
Standards  
標準  
기준  
Стандарты

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# Overview

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- General comments on electrostatic measurements and measurement methods.
  - Charge, voltage and electric field
  - Measuring charge - coulombmeter and Faraday cup
  - Measuring voltage - electrostatic voltmeters
  - Measuring electric field - electrostatic fieldmeters
- Review of E43 - 0301
  - what it contains
  - what areas are in need of review and additions
  - what has been done so far

# Why measure charge?

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- Charge measurement may serve as semiconductor characterization tool (work function of materials, mobile charge density, doping density, etc.)
- Measurements in semiconductor manufacturing:
  - Electrostatic discharge (ESD) hazard detection
    - integrated circuits, reticles

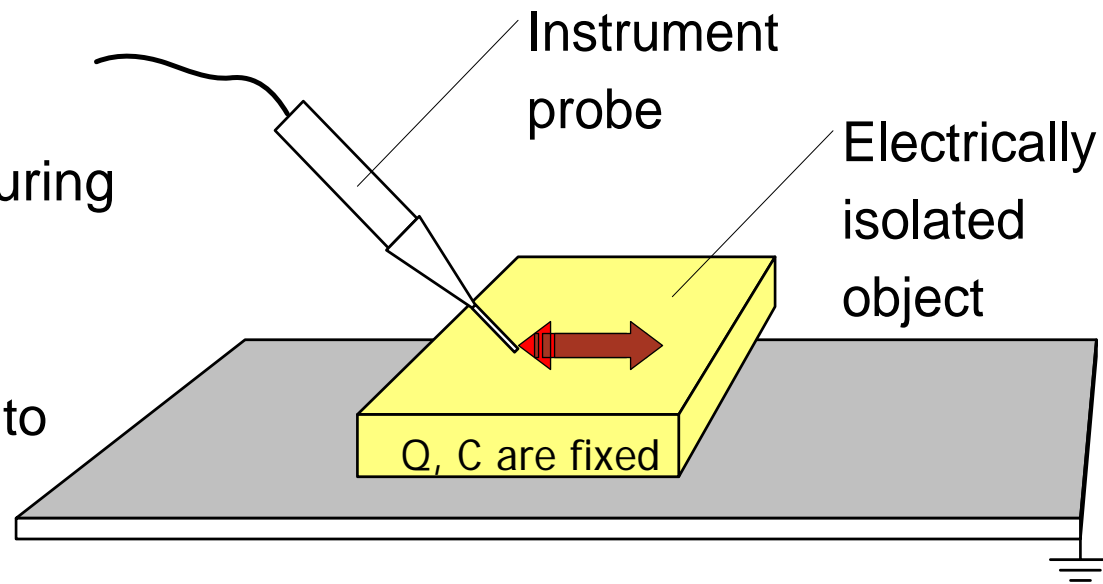
# Why measure charge (cont.)?

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- ESD may also cause an electromagnetic interference (EMI) problems
  - Equipment process interruption
- Prevent contamination via electrostatic attraction
  - Wafers, flat panel displays (FPD)
- Restrict damage due to field induced migration of material
  - Wafers
  - Reticles

# How to measure charge?

- Measurements in electrostatic systems require very high input impedance of the measuring instrument:
  - Charge is limited,
  - Electrical state of the measured object has to be preserved.
- Input impedance of the meter has to be much higher than that of the object being measured.



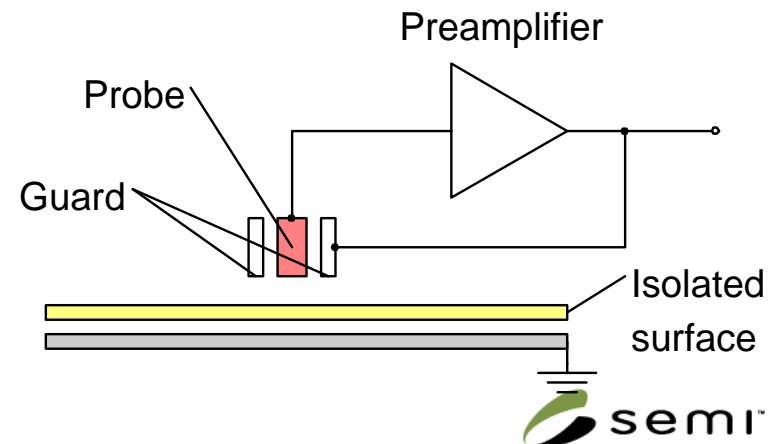
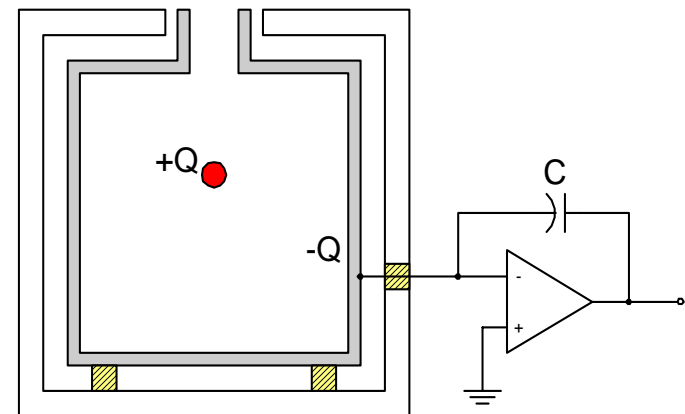
# High input impedance techniques

- Non-contacting methods:
  - Lack of physical contact assures that the input impedance is high

Instruments:

- The Faraday cup (pail) with a coulombmeter,
- Fieldmeters,
- Induction probes,
- Electrostatic voltmeters

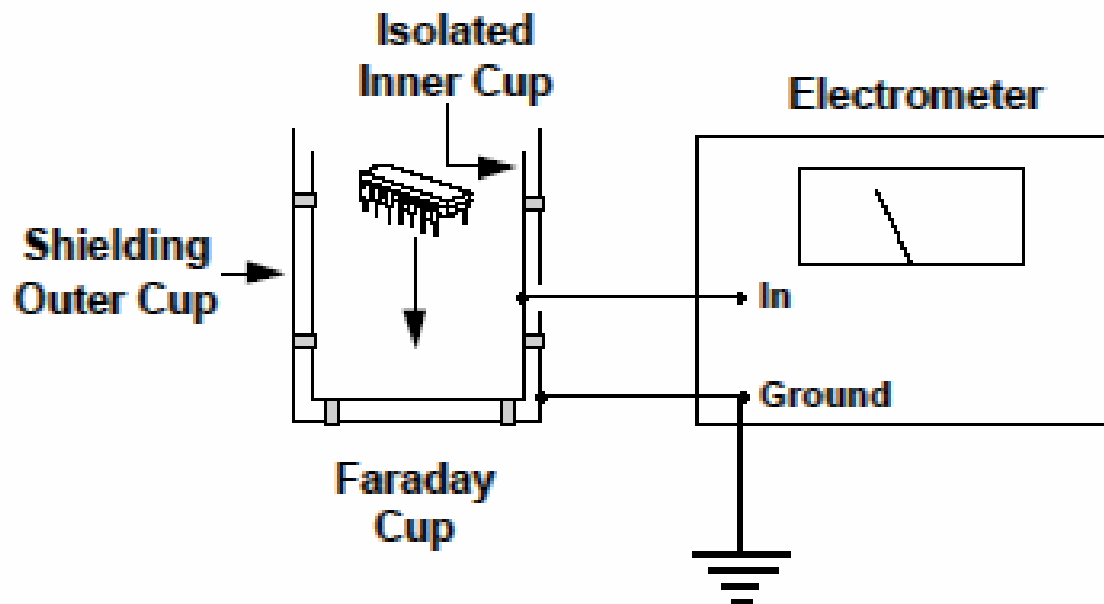
- Contacting methods:
  - Electrometers



# Charge measurement techniques in E43 - Coulombmeter

- Technique allowing for direct measurement of the charge – use of coulombmeter/electrometer
- Not always convenient and/or feasible
- Measures the net charge

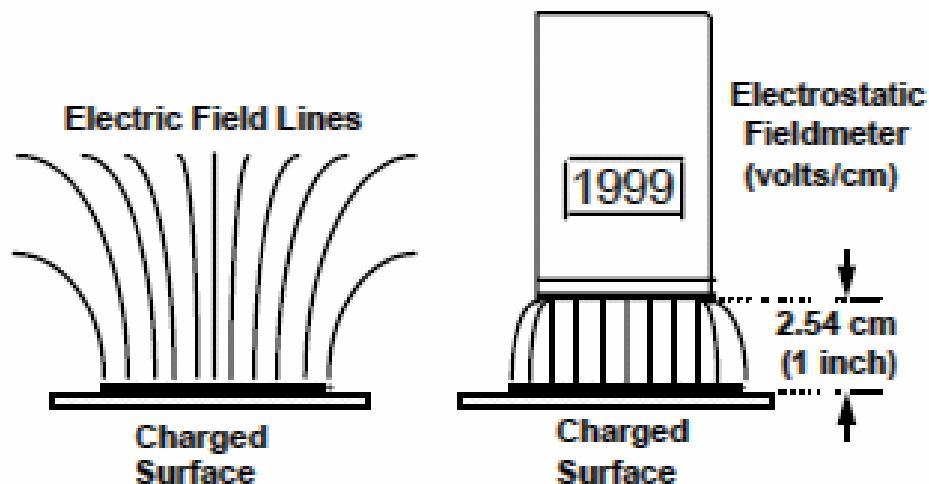
$$Q = C \cdot V$$



# Fieldmeter measurements

- Measures electric field  $E$
- Need to know the object-to-ground capacitance  $C$
- Charge  $Q$  can be calculated
- Spatial resolution not too good
- Arc-over hazard if the meter is too close to the measured object

$$Q = C \cdot E \cdot d$$

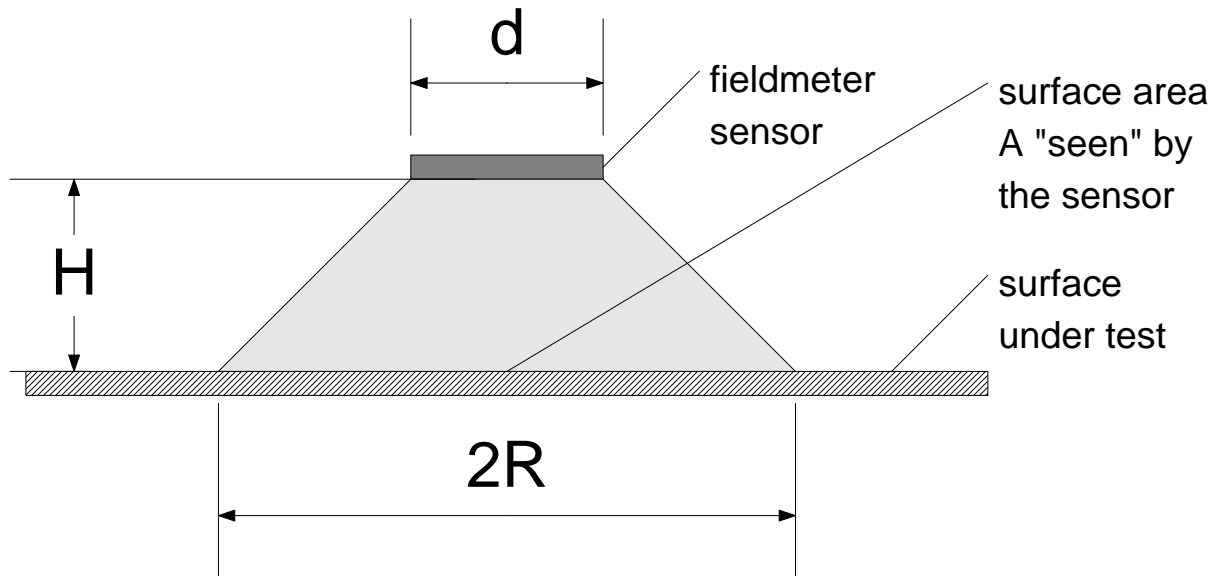




# Fieldmeter measurements, cont.

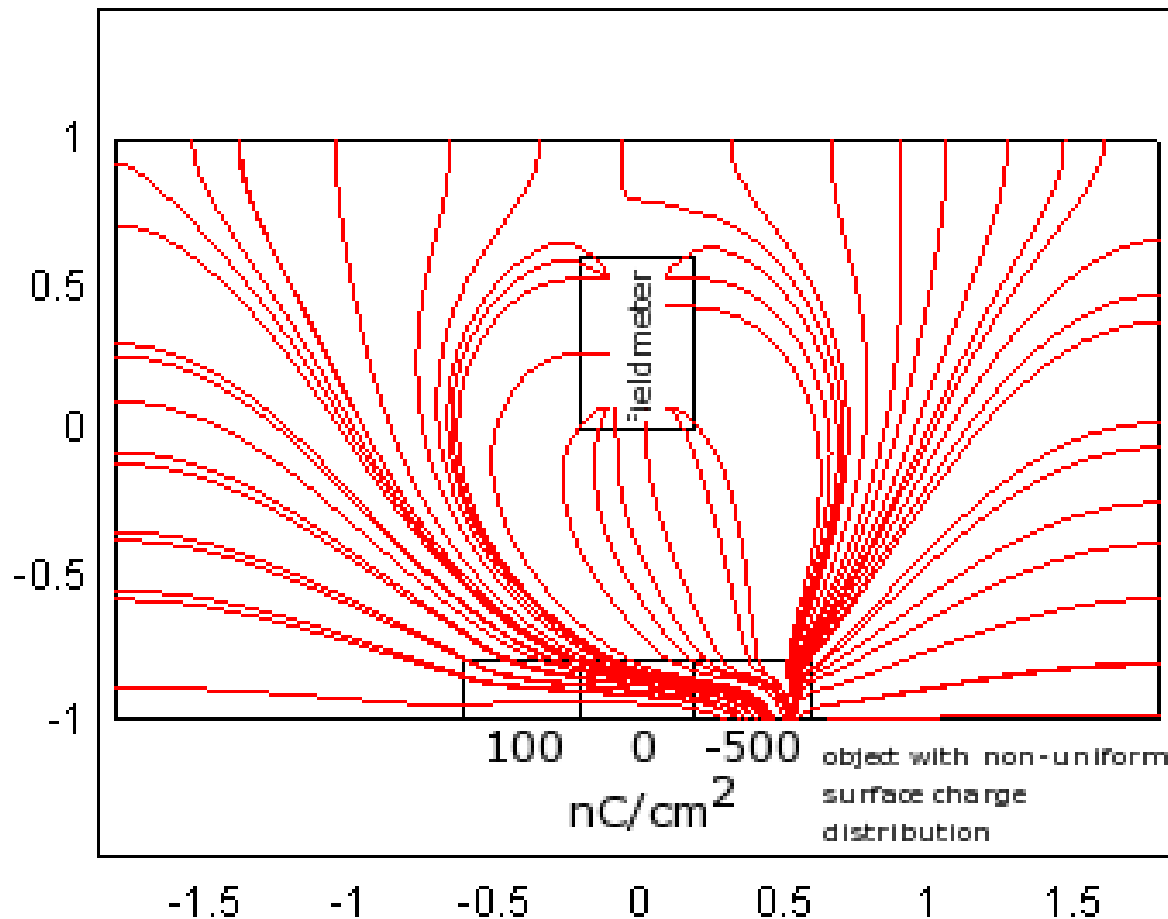
- If the capacitance is not known, the surface charge still can be theoretically approximated (assuming uniform distribution):

$$Q = \frac{2\varepsilon_0 \cdot E \cdot A}{\left(1 - \frac{H}{\sqrt{R^2 + H^2}}\right)}$$



# Fieldmeter measurements, cont.

Electric field lines



fieldmeter may distort the original electric field

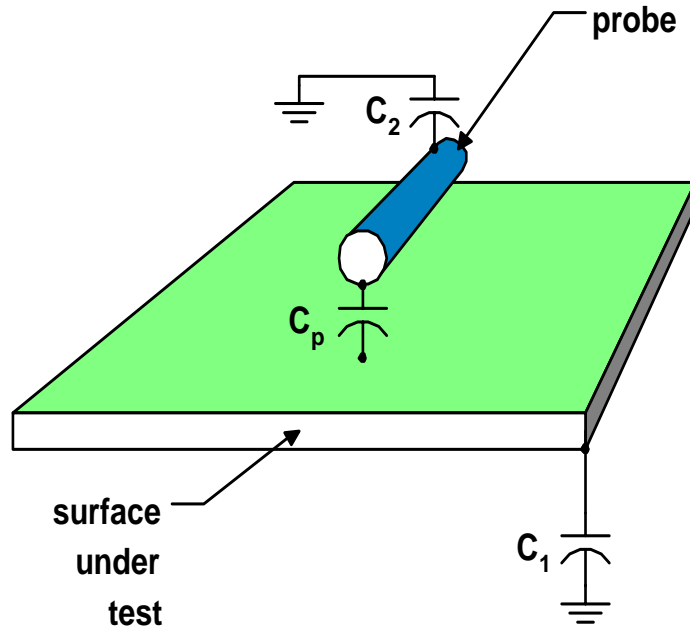
# Electrostatic voltmeter measurements

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- Measures voltage, not field. Field can be calculated, if necessary
- Good spatial resolution
- No arc-over hazard, the sensor is at the potential of the measured surface

$$Q = C \cdot V$$

# Electrostatic voltmeter measurements, cont.

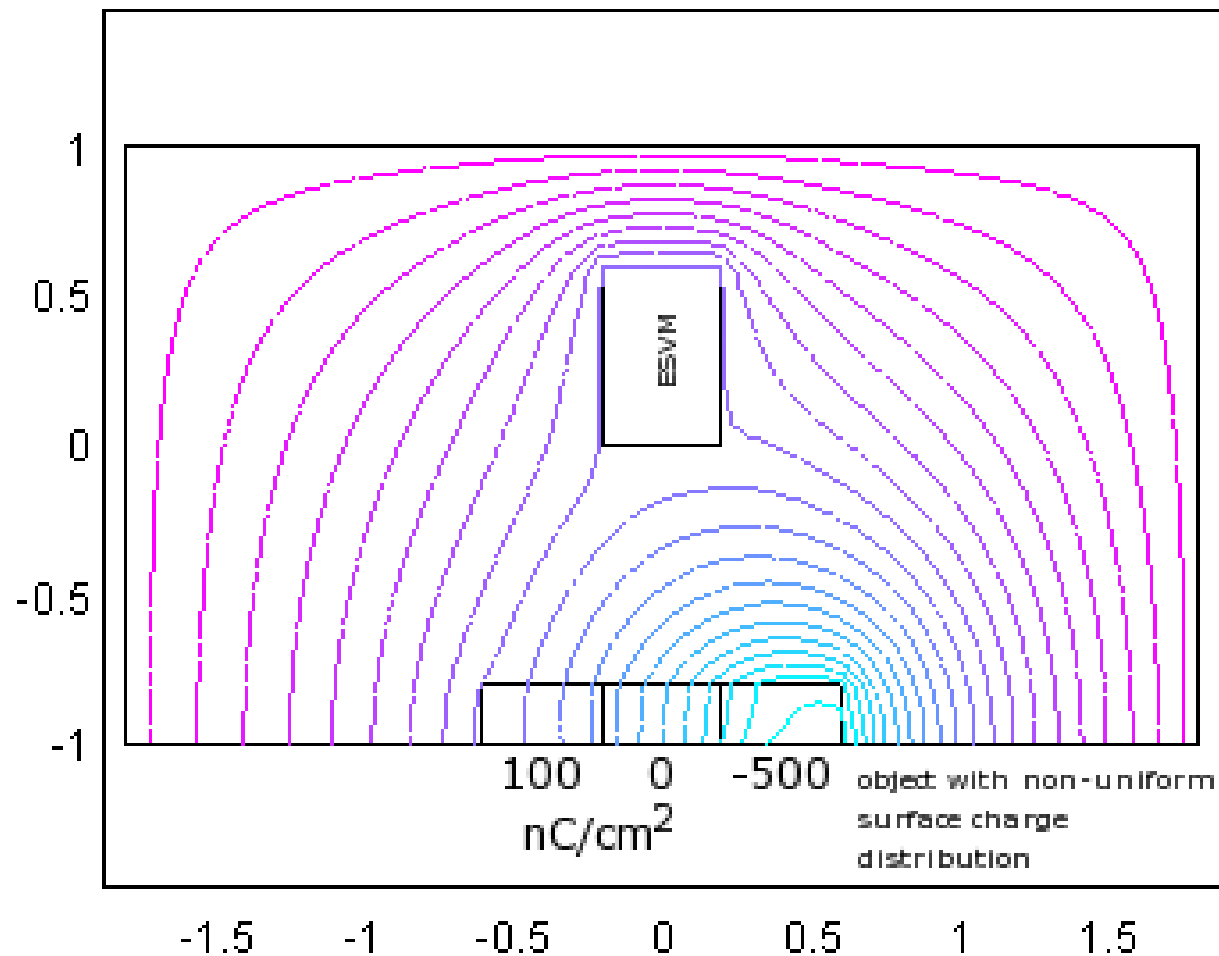


$$V = V_{\text{surface}} = V_{\text{probe}}$$

$$V = \frac{Q}{C_1 + C_p}$$

# Electrostatic voltmeter measurements, cont.

Equipotential lines



# Comments on field and voltage measurements

**Table 1 – Recommended Equipment Electrostatic Levels**

Year Node	Electrostatic Discharge, nC	Electrostatic Field, V/cm    V/inch	
		2000 180 nm	2.5–10
2002 130 nm	2.0	150	375
2003 100 nm	1.5	125	300
2004 90 nm	1.0	100	250
2006 70 nm	0.6	80	200
2007 65 nm	0.5	70	175
2009 50 nm	0.3	55	140
2010 45 nm	0.25	50	125
2013 32 nm	0.125	35	88
2015 25 nm	0.08	28	70
2018 18 nm	0.04	20	50

- Recommended equipment electrostatic levels in E78 are based on 10 pF capacitance

# Proposed changes to E43

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- Change in the title and scope (much broader: electrostatic measurements instead of electrostatic charge measurements)
- New section added: “Electrostatic discharge measurements”
  - Describes methods and instrumentation for the discharge measurements
- Structure changes, i.e. “Performance verification” of instrumentation moved to “Measurement” section
- New related information sections with examples

# Related information – new additions

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- Electric field, voltage and charge
  - discussion of generalized cases for the charge, electric field and voltage measurements on flat surfaces
  - advantages and disadvantages of each of the test methods
- Correlation between electric charge, electric field, and electric potential
  - basic information on dependencies between field, voltage and charge



# Conclusions

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- E43 should become a charge measurement guide referenced by other SEMI standards (E78, E129).
- Your feedback in that matter is very much needed and appreciated!
- Please participate in the E43 review process, meeting of the EOS/ESD TF on Tue., March 6th, 1:30-4:30 p.m.